

INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary) JUN 1 1 2001					Atty Docket No. M-9197 US		Serial No. 09/469,652	
					Wierer, Jr., et al.			
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		Document	Date	Country	Class	Subclass	Yes	N
C. C.	AG	11220168	8-10-99	Japan (Abstract)				
C.C.	AH	11-220168	8-10-99	Japan				
C.c.	AI	EP0 926744 A2	6-30-99	EPO	-	_		
C.C.	AJ	06045651	2-18-94	Japan (Abstract)	_			
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C.C.	AL	DE 4113 969A1	11-5-92	Germany				
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C.C.	AO	60102733	6-6-85	Japan (Abstract)		_	-	T
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2.0.	AQ	International Search Report for International application No. PCT/US 00/35184 filed 21/12/2000						
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	who		Date Considered	Sept. 2	0, 20			
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